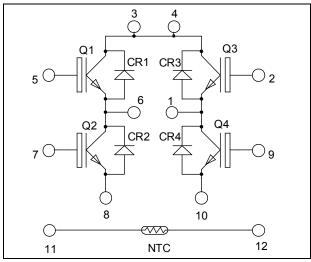
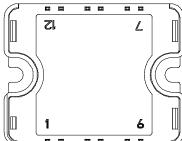
Full - Bridge High speed Trench + Field Stop IGBT4 Power Module







Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current	= 25°C	50	
I_{C}	$T_C = 80^{\circ}C$	= 80°C	25	Α
I_{CM}	Pulsed Collector Current $T_C =$	= 25°C	100	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Power Dissipation		165	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.78	2.05	2.42	V
V _{CE(sat)}	Collector Ellitter Saturation Voltage	$I_C = 25A$ $T_j = 150^{\circ}C$		2.6		V	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 0.85 \text{ mA}$		5.3	5.8	6.3	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				150	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		1430		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		95		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		75		
Q_{G}	Gate charge	$V_{GE} = 15V, I_{C} = 25A$ $V_{CE} = 960V$		115		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		27		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		41		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600 \text{V}$ $I_{\text{C}} = 25 \text{A}$		277		ns
T_{f}	Fall Time	$R_G = 19\Omega$		17		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)		26		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		35		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 25A$		347		ns
T_{f}	Fall Time	$R_G = 19\Omega$		50		
Eon	Turn on Energy	$V_{GE} = \pm 15V \ V_{Bus} = 600V$ $T_j = 150^{\circ}C$		2.4		mJ
E_{off}	Turn off Energy	$\begin{bmatrix} I_C = 25A \\ R_G = 19\Omega \end{bmatrix} \qquad T_j = 150^{\circ}C$		1.4		1110
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 600V$ $t_p \le 10\mu s$; $T_j = 150$ °C		90		A
R_{thJC}	Junction to Case Thermal Resistance				0.9	°C/W

Reverse diode ratings and characteristics (per diode)

Symbol	Characteristic	racteristic Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V _R =1200V				100	μΑ
I_F	DC Forward Current		Tc = 80°C		30		A
		$I_F = 30A$			2.6	3.1	
V_{F}	Diode Forward Voltage	$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{j} = 125^{\circ}C$		1.8		
4	Payarga Pagayary Tima	Time	$T_j = 25$ °C		300		200
t_{rr}	Reverse Recovery Time	$I_F = 30A$ $V_R = 800V$	$T_{j} = 125^{\circ}C$		380		ns
0	Reverse Recovery Charge	$di/dt = 200 A/\mu s$	$T_j = 25$ °C		360		пC
Q _{rr}			$T_{j} = 125^{\circ}C$		1700		IIC
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W



Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V	
T_{J}	Operating junction temperature range			-40	175		
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C	
T_{STG}	Storage Temperature Range			-40	125	C	
$T_{\rm C}$	Operating Case Temperature				125		
Torque	Mounting torque	To heatsink	M4	2	3	N.m	
Wt	Package Weight				80	g	

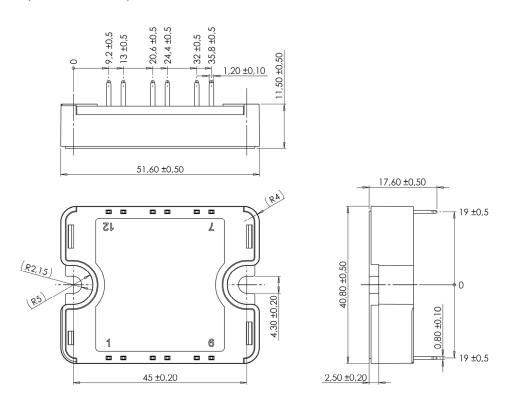
Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

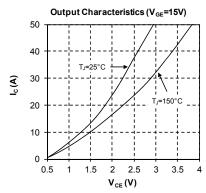
Package outline (dimensions in mm)

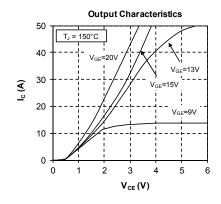


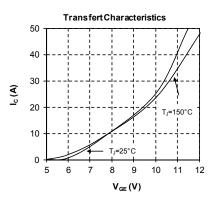
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

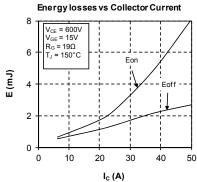


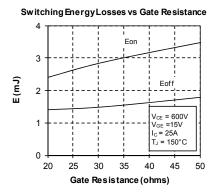
Typical Performance Curve

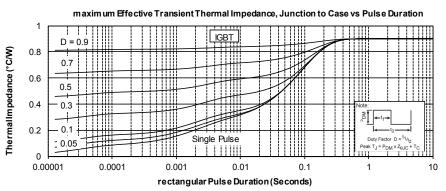






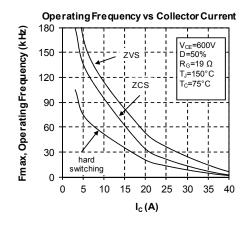


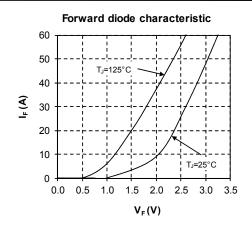




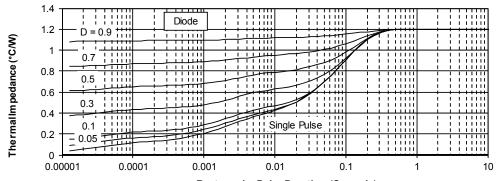


Power Matters.™





maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



Rectangular Pulse Duration (Seconds)



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